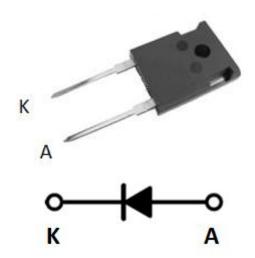


# FRED Soft Recovery Diode, 30A

#### **Features:**

- Superfast Recovery
- 175° C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction



Product Summary		
VR	600 V	
lf(AV)	30A	
trr	40ns	

#### **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings					
Parameter	Symbol	Test Conditions	Values	Units	
Repetitive peak reverse voltage	Vrrm		600	V	
Continuous forward current	lf(AV)	Tc =110° C	30		
Single pulse forward current	IFSM	Tc =25° C	240	Α	
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	60		
Operating junction	Tj		175	° C	
Storage temperatures	Tstg		-55 to +175	° C	

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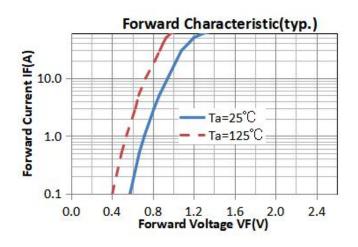


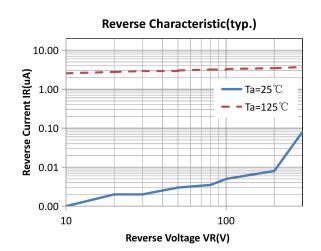
Electrical characteristics (Ta=25° C unless otherwise specified)						
Parameter	Symbol	<b>Test Conditions</b>	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	Ir=100⊬A	600			
Blocking voltage	$V_R$	IR-100PA	000			
Forward voltage (Per Diode)	VE	Ir=30A		1.10	1.40	V
	VF	IF=30A, Tj =125° C		0.98	1.20	
Reverse leakage current(Per Diode)	Vr= Vrrm			20	μ <b>Δ</b>	
		Tj=150° C, Vr=600V			200	170
Reverse recovery time(Per Diode)		I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A				nc
	trr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		40	45	ns

### Thermal characteristics

Paramter	Symbol	Тур	Max	Units
Junction-to-Case	$R_{ heta JC}$	0.8	2.0	°C/W

## **Electrical performance (typic)**



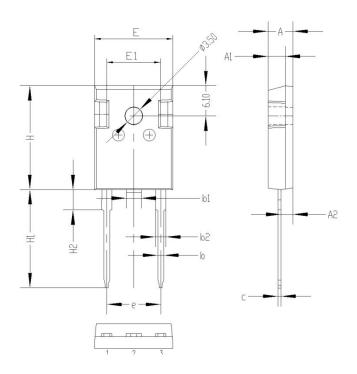


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## **Package Information**

#### **TO-247-2L PACKAGE**



Cymphol	Dimensions(millimeters)		
Symbol	Min.	Max.	
Α	4.8	5.2	
A1	3.3	3.7	
A2	2.1	2.5	
b	1	1.4	
b1	2.8	3.2	
b2	1.9	2.3	
С	0.4	0.8	
е	10.7	11.1	
Е	15.6	16	
E1	10.6	11	
Н	20.8	21.2	
H1	19.4	20.4	
H2	3.9	4.3	
G	5.9	6.3	
ΦР	3.3	3.7	

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